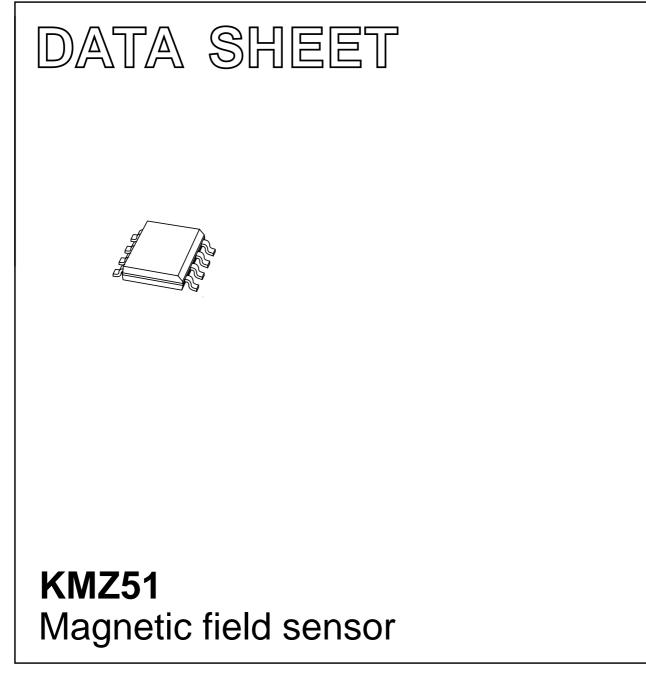
DISCRETE SEMICONDUCTORS



Product specification Supersedes data 1998 Mar 24 2000 Jun 13



Philips Semiconductors

Product specification

Magnetic field sensor

FEATURES

- High sensitivity
- Integrated compensation coil
- Integrated set/reset coil.

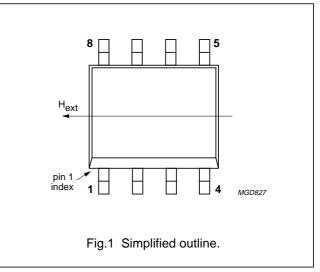
APPLICATIONS

- Navigation
- · Current and earth magnetic field measurement
- Traffic detection.

DESCRIPTION

The KMZ51 is an extremely sensitive magnetic field sensor, employing the magnetoresistive effect of thin-film permalloy. The sensor contains one magnetoresistive Wheatstone bridge and integrated compensation and set/reset coils. The integrated compensation coil allows magnetic field measurement with current feedback loops to generate an output that is independent of drift in sensitivity. The orientation of sensitivity may be set or changed (flipped) by means of the integrated set/reset coil. A short current pulse should be applied to the compensation coil to recover (set) the sensor after exposure to strong disturbing magnetic fields. A negative current pulse will reset the sensor to reversed sensitivity. By use of periodically alternated flipping pulses and a lock-in amplifier, output is made independent of sensor and amplifier offset.

PINNING PIN SYMBOL DESCRIPTION 1 flip coil +I_{flip} 2 V_{CC} bridge supply voltage 3 GND ground 4 $+I_{comp}$ compensation coil 5 compensation coil $-I_{comp}$ 6 -Vo bridge output voltage 7 +Vo bridge output voltage 8 $-\mathbf{I}_{flip}$ flip coil



QUICK REFERENCE DATA

SYMBOL	PARAMETER	MIN.	TYP.	MAX.	UNIT
V _{CC}	bridge supply voltage	-	5	8	V
S	sensitivity (uncompensated)	12	16	-	mV/V kA/m
Voffset	offset voltage	-1.5	-	+1.5	mV/V
R _{bridge}	bridge resistance	1	-	3	kΩ
R _{comp}	compensation coil resistance	100	170	300	Ω
A _{comp}	compensation coil field factor; note 1	19	22	25	$\frac{A/m}{mA}$

KMZ51

KMZ51

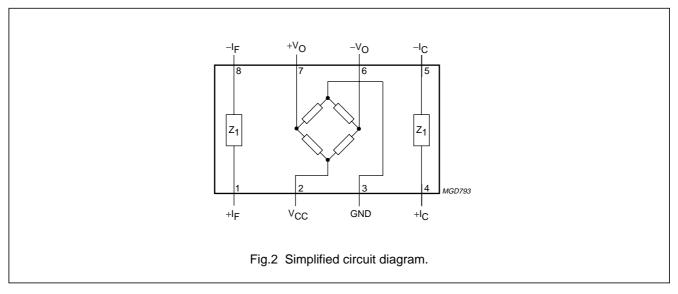
SYMBOL	PARAMETER	MIN.	TYP.	MAX.	UNIT
R _{flip}	flip coil resistance	1	2	3	Ω
I _{flip (min)}	minimum recommended flipping current; note 2	800	1000	1200	mA
t _{flip (min)}	minimum flip pulse duration; note 2	1	3	100	μs

Notes

1. The compensation coil generates a field $H_{comp} = A_{comp} \times I_{comp}$ in addition to the external field H_{ext} . Sensor output will become zero if $H_{ext} = -H_{comp}$.

2. Average power consumption of the flipping coil, defined by current, pulse duration and pulse repetition rate may not exceed the specified limit, see Chapter "Limiting values".

CIRCUIT DIAGRAM



LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
V _{CC}	bridge supply voltage	-	9	V
P _{tot}	total power dissipation	-	130	mW
T _{stg}	storage temperature	-65	+150	°C
T _{bridge}	bridge operating temperature	-40	+125	°C
I _{comp}	maximum compensation current	-	15	mA
I _{flip (max)}	maximum flipping current	-	1500	mA
P _{flip (max)}	maximum flipping power dissipation	-	50	mW
V _{isol}	voltage between isolated systems: flip coil and Wheatstone bridge; compensation coil and Wheatstone bridge; flip coil and compensation coil	_	60	V

KMZ51

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	VALUE	UNIT
R _{th j-a}	thermal resistance from junction to ambient	155	K/W

CHARACTERISTICS

 T_{amb} = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _{CC}	bridge supply voltage		_	5	8	V
Hy	operating range in sensitive direction		-0.2	-	+0.2	kA/m
H _x	operating range perpendicular to sensitive direction		-0.2	-	+0.2	kA/m
S	sensitivity	open circuit	12	16	-	mV/V kA/m
TCS	temperature coefficient of sensitivity	T _s = -25 to +125 °C	-	0.31	_	%/K
TCVO	temperature coefficient of output voltage	V _{CC} = 5 V; T _{amb} = -25 to +125 °C	-	-0.4	-	%/K
		I _{CC} 3 mA; T _{amb} = −25 to +125 °C	-	-0.1	-	%/K
R _{bridge}	bridge resistance	resistance pins 2 to 3	1	-	3	kΩ
TCR _{bridge}	temperature coefficient of bridge resistance	T _{bridge} = -25 to +125 °C	-	0.3	-	%/K
Voffset	offset voltage		-1.5	0	+1.5	mV/V
TCV _{offset}	temperature coefficient of offset voltage	T _{bridge} = -25 to +125 °C	-3	0	+3	μ <u>V/V</u> K
FH	hysteresis of output voltage		-	-	2	%FS
R _{comp}	resistance of compensation coil	resistance pins 4 to 5	100	170	300	Ω
A _{comp}	field factor of compensation coil		19	22	25	A/m mA
R _{flip}	resistance of set/reset conductor	resistance pins 1 to 8	1	2	3	Ω
TCR _{flip}	temperature coefficient of resistance of set/reset coil	$T_{flip} = -25 \text{ to } +125 ^{\circ}\text{C}$	-	0.39	-	%/K
I _{flip}	recommended flipping current for stable operation		±800	±1000	±1200	mA
t _{flip}	flip pulse duration		1	3	100	μs
R _{isol}	isolating resistance	resistance pins 1 to 2, 1 to 4 and 2 to 4	1	-	-	mΩ
V _{isol}	voltage between isolated systems	voltage pins 1 to 2, 1 to 4 and 2 to 4	-	-	50	V
f	operating frequency		0	-	1	MHz

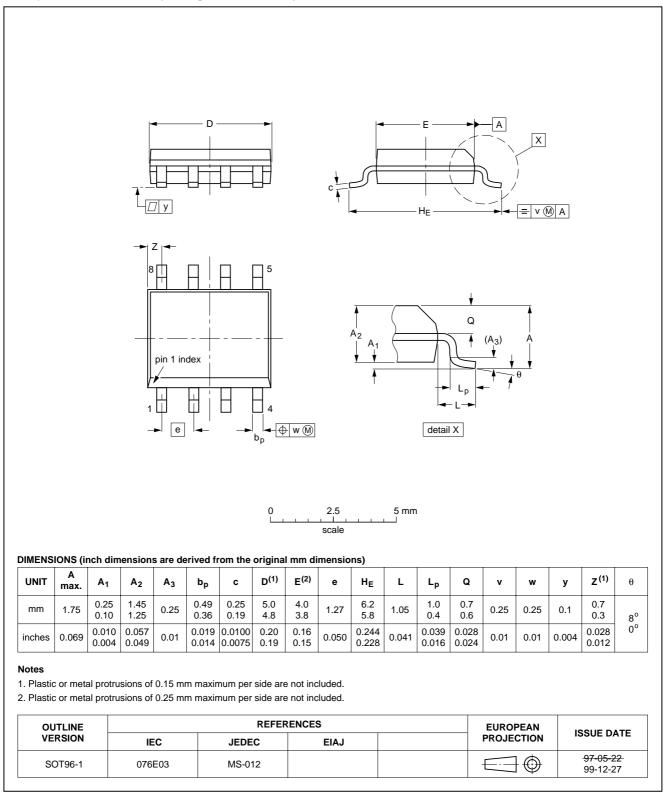
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Magnetic field sensor

PACKAGE OUTLINE

SO8: plastic small outline package; 8 leads; body width 3.9 mm



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DATA SHEET STATUS

DATA SHEET STATUS	PRODUCT STATUS	DEFINITIONS (1)
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
Preliminary specification Qualification		This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.
Product specification	Production	This data sheet contains final specifications. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.

Note

1. Please consult the most recently issued data sheet before initiating or completing a design.

DEFINITIONS

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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Product specification

KMZ51

NOTES

2000 Jun 13

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